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View Online at https://aerobasegroup.com/nsn/5961-01-622-7020 **Inclosure Material:** Plastic **Overall Length:** 0.114 inches **Terminal Length:** 0.021 inches **Overall Height:** 0.040 inches **Overall Width:** 0.094 inches **Function For Which Designed:** Detector and switching **Mounting Facility Quantity:** Joint Electronic Device Engineering Council/jedec/case Outline Designation: **Component Name And Quantity:** 2 semiconductor device diode **Mounting Method: Terminal Features Provided:** Very high speed Voltage Rating In Volts Per Characteristic: 30.0 breakdown voltage, dc 2nd semiconductor device diode **Current Rating Per Characteristic:** 200.0 milliamperes forward current, dc 2nd semiconductor device diode **Power Rating Per Characteristic:** 225.0 milliwatts forward power dissipation, dc 2nd semiconductor device diode **Capacitance Rating In Picofarads:** 7.6 and 10.0 2nd semiconductor device diode **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Product Name:** Diode **Terminal Type And Quantity:** 3 printed circuit Shelf Life: N/a **Unit Of Measure: Demilitarization:**

No

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